		Complete If Known		
FINE ORMATION DISCLOS	SURE	Application Number	10/625,914	
CITATION FEB 0 9 2004 PTO-1449		Filing Date	July 22, 2003	
		First Named Inventor	Ely K. Tsern et al.	
		Art Unit	2818	
		Examiner Name	Lam, David	
TRANSPORT 1 of	2	Attorney Docket Number	60809-0137	

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Complete If Known **QRMATION DISCLOSURE Application Number** 10/625,914 July 22, 2003 Filing Date **CITATION** First Named Inventor Ely K. Tsem et al. Art Unit 2818 PTO-1449 **Examiner Name** Lam, David Attorney Docket Number 60809-0137 of 2

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Signature Considered V/V7	Examiner Signature	HA Fran	Date Considered	4/04
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